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DATE MAILED: 08/20/2002

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/826,472	04/04/2001	Bin Yu	P1296	6214	
75	590 08/20/2002				
LaRiviere, Grubman & Payne, LLP			EXAMINER		
P.O. Box 3140 Monterey, CA 93942			POMPEY, RON EVERETT		
			ART UNIT	PAPER NUMBER	
			2812		

Please find below and/or attached an Office communication concerning this application or proceeding.

	, 4.			JIM			
	Application No.		Applicant(s)	41.5			
Office Action Comments	09/826,472		YU, BIN				
Office Action Summary	Examiner		Art Unit				
Ti	Ron E Pompey		2812				
The MAILING DATE of this communication app Period for Reply	ars on the cover sh	et with the c	correspondence add	dr ss			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period v - Failure to reply within the set or extended period for reply will, by statute, - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	36(a). In no event, however, my within the statutory minimum will expire SIX (6). Cause the application to become	ay a reply be tin of thirty (30) day MONTHS from me ABANDONE	nely filed s will be considered timely the mailing date of this co	mmunication.			
1) Responsive to communication(s) filed on	·						
2a) ☐ This action is FINAL . 2b) ☑ Thi	is action is non-final.						
3) Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims							
4)⊠ Claim(s) <u>1-20</u> is/are pending in the application							
4a) Of the above claim(s) <u>19</u> is/are withdrawn from consideration.							
5) Claim(s)is/are allowed.							
6)⊠ Claim(s) <u>1-18</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or	election requirement						
Application Papers	·						
9) The specification is objected to by the Examiner							
10)☐ The drawing(s) filed on is/are: a)☐ accept	ted or b) objected to	by the Exar	niner.				
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.							
If approved, corrected drawings are required in reply to this Office action.							
12) The oath or declaration is objected to by the Examiner.							
Priority under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.	C. § 119(a)	-(d) or (f).				
a) ☐ All b) ☐ Some * c) ☐ None of:							
1. Certified copies of the priority documents	have been received.						
2. Certified copies of the priority documents							
3. Copies of the certified copies of the prioriapplication from the International Burg* See the attached detailed Office action for a list of	eau (PCT Rule 17.2(a)).		stage			
14) Acknowledgment is made of a claim for domestic	priority under 35 U.S	.C. § 119(e)) (to a provisional a	application).			
a) The translation of the foreign language prov 15) Acknowledgment is made of a claim for domestic							
Attachment(s)							
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 	5) Notice		(PTO-413) Paper No(s) atent Application (PTO-				
S. Patent and Trademark Office							



Application/Control Number: 09/826,472

Art Unit: 2812

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1, 2, 4-6, 8, 9, 11, 12 and 14 rejected under 35 U.S.C. 102(b) as being anticipated by Gardner et al. (US 5,963,810).

Gardner discloses the limitations of:

For 1, 2, 4-6, 8, 9, 11, 12 and 14:

depositing a first nitride film (303, fig. 3A) on a semiconductor substrate;

depositing a high-k material (305, fig. 3B) on the first nitride (col. 5, Ins. 30-64 and col. 3, Ins. 25-32),

depositing a second nitride film on the high-k material (col. 6, lns. 13-20); and completing fabrication of the device (col. 6, lns. 1-12).

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Application/Control Number: 09/826,472

Art Unit: 2812

4. Claims 3, 7, 10, 13 and 15-19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et al. (US 5,963,810) as applied to claim 1 above, and further in view of Dautartas et al. (US 6,124,158).

Gardner discloses the claimed invention except:

5. For where Dautartas discloses:

For claims 3, 7, 13 and 15-17:

wherein the nitride films are deposited by using an atomic layer deposition (ALD) technique (col. 7, Ins. 15-30).

Therefore it would have been obvious to one of ordinary skill in the art at the time of the invention to form the nitride layers using an ALD technique, because this deposition technique provides excellent uniformity and surface conformity of thin insulator films.

6. For claims 10 and 18 -19 the examiner takes *official notice* that it is well know to form a gate from a group of materials consisting essentially of polysilicon and polysilicon-germanium, and that using a photoresist is part of know etching processes.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ron E Pompey whose telephone number is (703) 305-3016. The examiner can normally be reached on flex schedule.

Ron Pompey
Art Unit: 2812

May 20, 2002

John F. Mabling Supervisory Estant Examiner

Technology Carrier 25:00